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NXP Semiconductors/Freescale Semiconductor, Inc. NX7002AKW,115

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**Distributor of NXP Semiconductors/Freescale Semiconductor, Inc. : Excellent Integrated** Datasheet of NX7002AKW,115 - MOSFET N-CH 60V SOT323 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

# **NX7002AKW**

60 V, single N-channel Trench MOSFET

**Product data sheet** 

### 1. Product profile

#### 1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### **1.2 Features and benefits**

- Very fast switching
- Trench MOSFET technology
- ESD protected

#### 1.3 Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

### 1.4 Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	60	V
V <sub>GS</sub>	gate-source voltage			-20	-	20	V
I <sub>D</sub>	drain current	$V_{GS}$ = 10 V; $T_{amb}$ = 25 °C	[1]	-	-	170	mA
Static character	Static characteristics						
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 100 mA; T <sub>j</sub> = 25 °C		-	3	4.5	Ω

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.







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### 2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 ☐ ☐ 2 SC-70 (SOT323)	G S 017aaa255

### 3. Ordering information

#### Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
NX7002AKW	SC-70	plastic surface-mounted package; 3 leads	SOT323	

### 4. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
NX7002AKW	AH%

[1] % = placeholder for manufacturing site code

### 5. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	60	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	170	mA
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 100 °C	[1]	-	100	mA
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	680	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	220	mW
			[1]	-	255	mW

```
NX7002AKW
```



## **NX7002AKW**

#### 60 V, single N-channel Trench MOSFET

Symbol	Parameter	Conditions		Min	Мах	Unit
		T <sub>sp</sub> = 25 °C		-	1060	mW
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drain diode						,
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	170	mA

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.
 Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

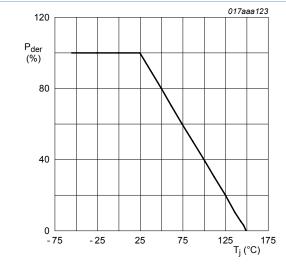
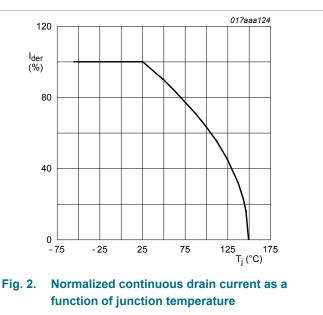


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

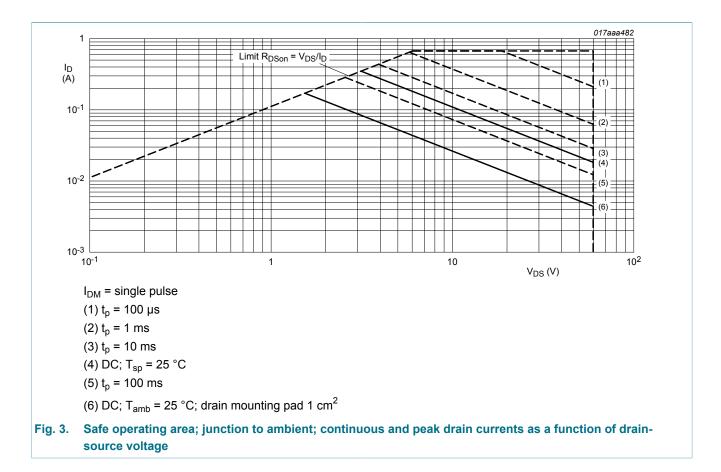


$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \text{ \%}$$



## **NX7002AKW**





## 6. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R <sub>th(j-a)</sub> thermal resistance	-	[1]	-	485	560	K/W	
from junction to ambient		[2]	-	420	480	K/W	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	115	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

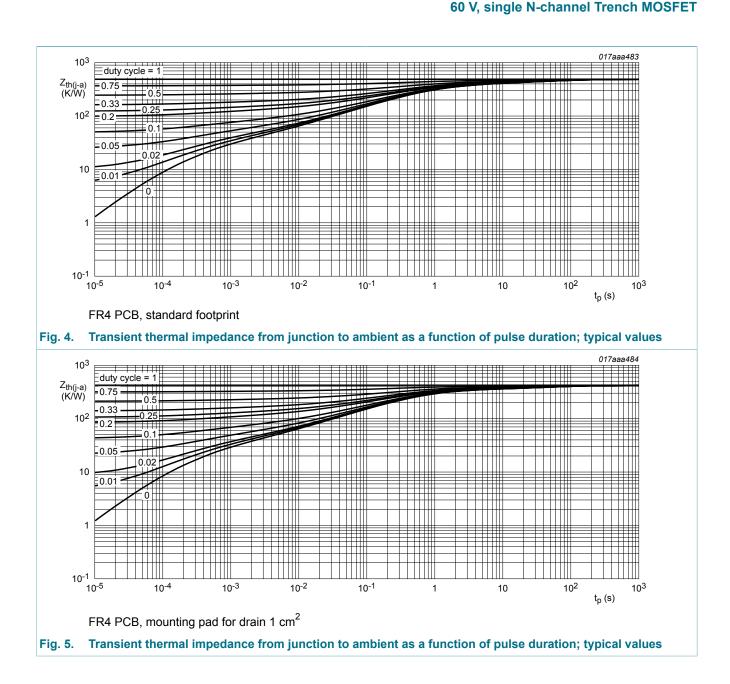
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.



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## 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Static characteristics							
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	60	-	-	V	
V <sub>GSth</sub>	gate-source threshold voltage	I <sub>D</sub> = 250 μA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C	1.1	1.6	2.1	V	
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = 60 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	1	μA	
		V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 150 °C	-	-	10	μA	

**Product data sheet** 



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#### 60 V, single N-channel Trench MOSFET

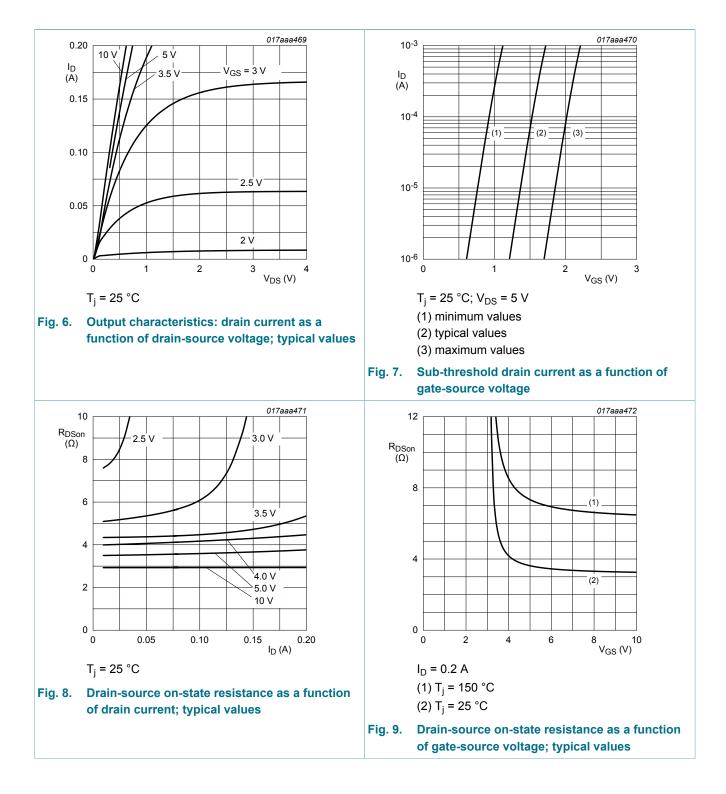
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
GSS gate leakage current		$V_{GS}$ = 20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	2	μA
		$V_{GS}$ = -20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	2	μA
		V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	0.5	μA
		$V_{GS}$ = -10 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	0.5	μA
		$V_{GS}$ = 5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	100	nA
		$V_{GS}$ = -5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	100	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 100 mA; T <sub>j</sub> = 25 °C	-	3	4.5	Ω
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 100 mA; T <sub>j</sub> = 150 °C	-	6.2	9.2	Ω
		$V_{GS}$ = 5 V; I <sub>D</sub> = 100 mA; T <sub>j</sub> = 25 °C	-	3.7	5.2	Ω
9 <sub>fs</sub>	forward transconductance	$V_{DS}$ = 10 V; I <sub>D</sub> = 200 mA; T <sub>j</sub> = 25 °C	-	230	-	mS
Dynamic cl	haracteristics		I			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 30 V; I <sub>D</sub> = 200 mA; V <sub>GS</sub> = 4.5 V;	-	0.33	0.43	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	0.12	-	nC
Q <sub>GD</sub>	gate-drain charge		-	0.09	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 10 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	11	17	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	3.4	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	1.4	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 40 V; R <sub>L</sub> = 250 Ω; V <sub>GS</sub> = 10 V;	-	6	12	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	7	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	20	40	ns
t <sub>f</sub>	fall time		-	14	-	ns
Source-dra	in diode		1			
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 115 mA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	0.47	0.7	1.2	V



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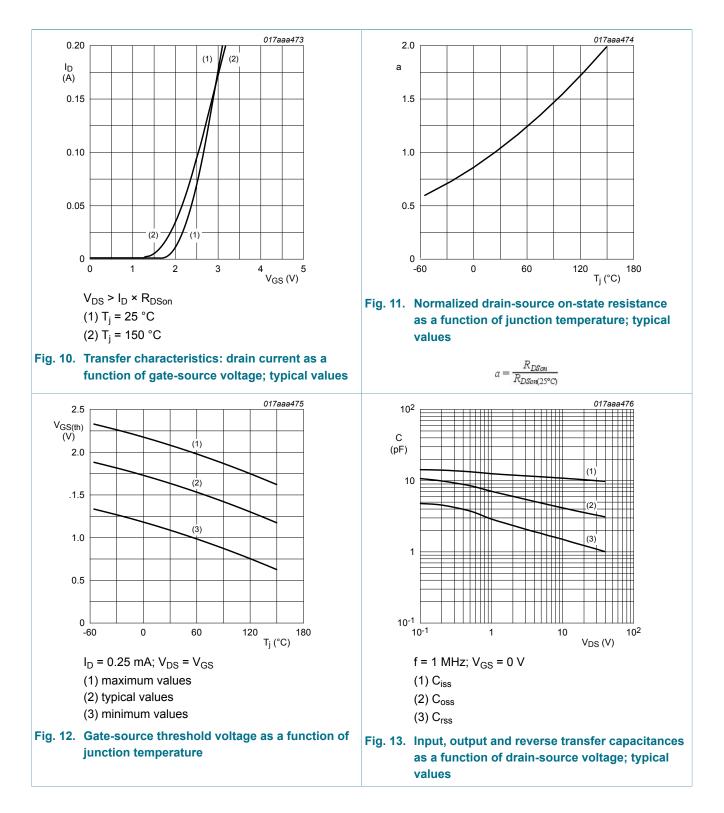




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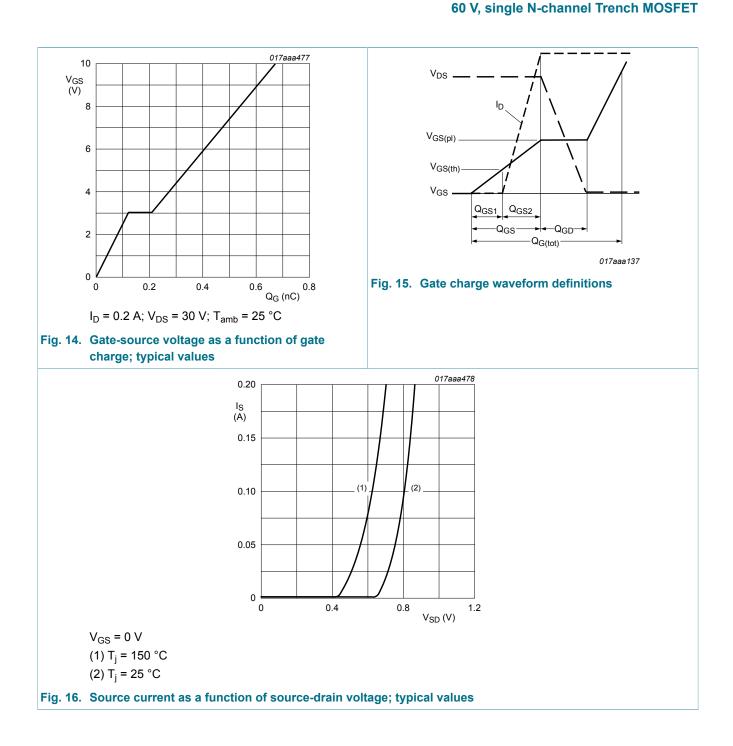




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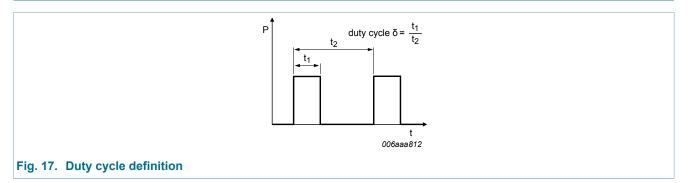




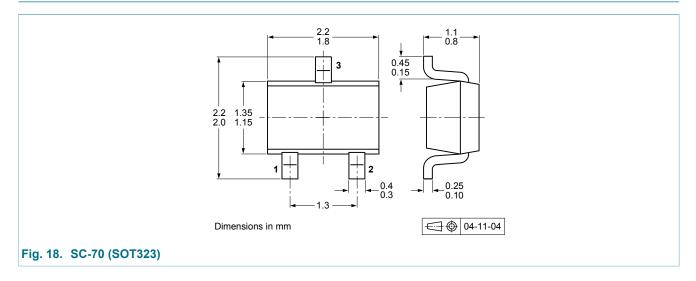
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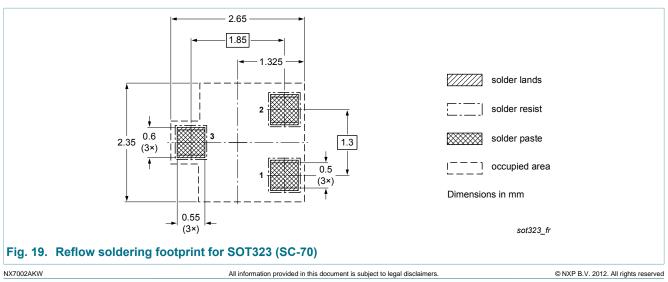
#### **Test information** 8.



#### **Package outline** 9.



### 10. Soldering





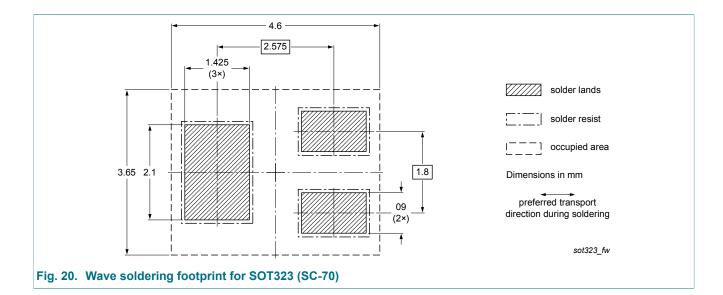


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### 11. Revision history

Table 8.	<b>Revision history</b>	

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NX7002AKW v.2	20120711	Product data sheet	-	NX7002AKW v.1
Modifications:	Characteristics: I <sub>GSS</sub>	s value corrected		
NX7002AKW v.1	20120301	Product data sheet	-	-



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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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